

# SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

N-Channel Silicon MOSFET

# **5LN01S** — General-Purpose Switching Device Applications

#### **Features**

- · Low ON-resistance
- · Ultrahigh-speed switching
- · 2.5V drive

#### **Specifications**

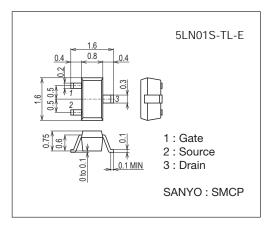
#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		50	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±10	V
Drain Current (DC)	ID		0.1	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	0.4	А
Allowable Power Dissipation	PD		0.15	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

This product is designed to "ESD immunity  $< 200V^*$ ", so please take care when handling.

#### **Package Dimensions**

unit : mm (typ) 7027-004

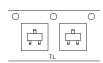


#### **Product & Package Information**

• Package : SMCP

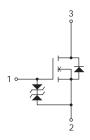
• JEITA, JEDEC : SC-75, SOT-416 • Minimum Packing Quantity : 3,000 pcs./reel

Packing Type: TL Marking





#### **Electrical Connection**



http://semicon.sanyo.com/en/network

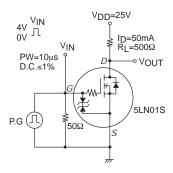
<sup>\*</sup> Machine Model

#### 5LN01S

#### Electrical Characteristics at Ta=25°C

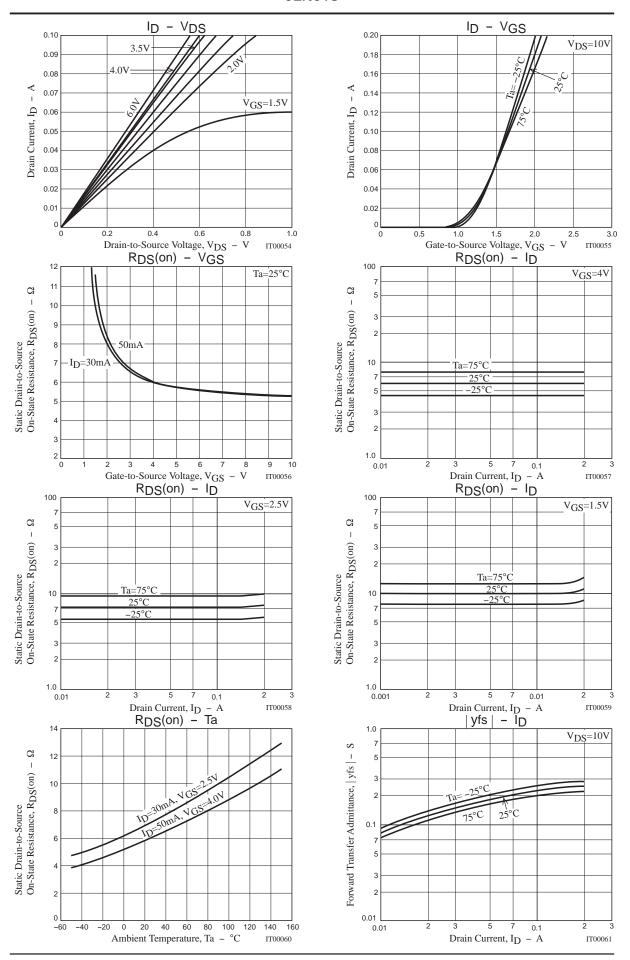
Doromotor	Complete	0 1111	Ratings				
Parameter	Symbol	Conditions	min	typ	max	Unit	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	50			V	
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =50V, V <sub>GS</sub> =0V			1	μΑ	
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V			±10	μΑ	
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =100μA	0.4		1.3	V	
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =50mA	0.13	0.18		S	
	RDS(on)1	ID=50mA, VGS=4V		6	7.8	Ω	
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)2	I <sub>D</sub> =30mA, V <sub>GS</sub> =2.5V		7.1	9.9	Ω	
	R <sub>DS</sub> (on)3	ID=10mA, VGS=1.5V		10	20	Ω	
Input Capacitance	Ciss			6.6		pF	
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		4.7		pF	
Reverse Transfer Capacitance	Crss			1.7		pF	
Turn-ON Delay Time	t <sub>d</sub> (on)			18		ns	
Rise Time	tr	Con amonified Took Circuit		42		ns	
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		190		ns	
Fall Time	tf			105		ns	
Total Gate Charge	Qg			1.57		nC	
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =100mA		0.20		nC	
Gate-to-Drain "Miller" Charge	Qgd	]		0.32		nC	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =100mA, V <sub>GS</sub> =0V		0.85	1.2	V	

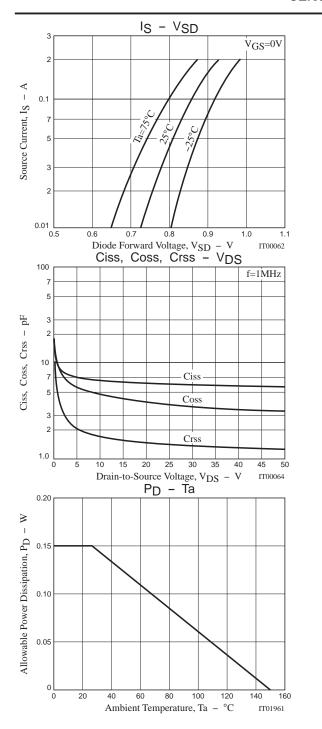
# Switching Time Test Circuit

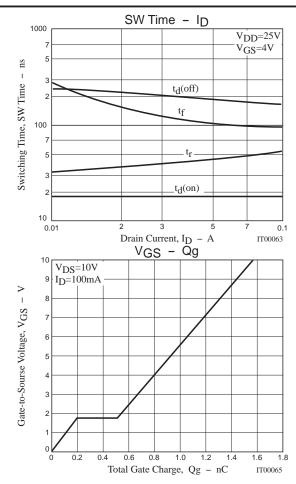


#### **Ordering Information**

Device Package		Shipping	memo	
5LN01S-TL-E SMCP		3,000pcs./reel	Pb Free	





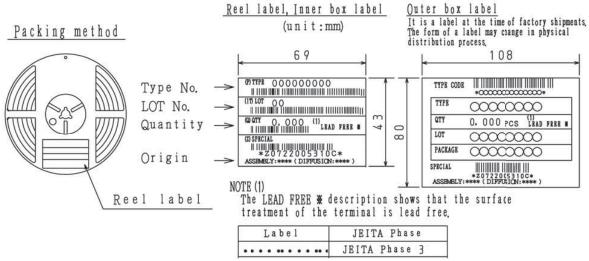


#### **Embossed Taping Specification**

5LN01S-TL-E

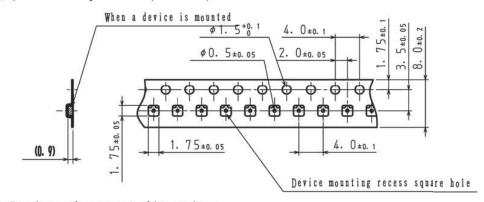
#### 1. Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing format		
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
SMCP	SMCP	3, 000	15, 000	90, 000	5 reels contained Dimensions:mm(external)	6 inner boses contained Dimensions:mm (external)	
					183×72×185	440×195×210	

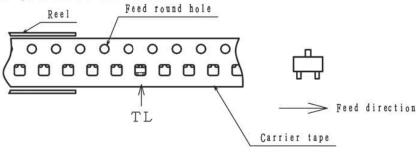


### 2. Taping configuration

2-1. Carrier tape size (unit:mm)



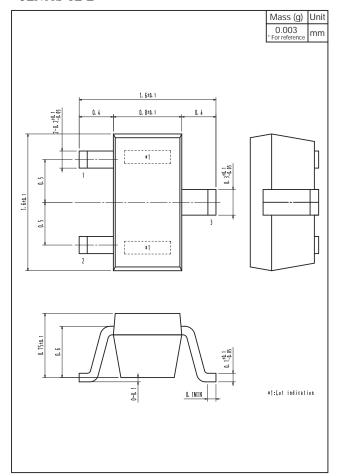
2-2. Device placement direction



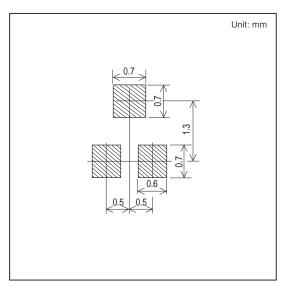
Those with one electrode terminal on the feed hole side ..... TL

# **Outline Drawing**

5LN01S-TL-E



# Land Pattern Example



Note on usage: Since the 5LN01S is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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